2 Channel Auto-Bidirectional Multi-Voltage Level Translator for Open-Drain and Push-Pull Applications

General Description

The ETQF0102 supports bidirectional voltage translation without the need for DIR pin which minimizes system effort. The ETQF0102 supports 5V tolerance on I/O port which makes it compatible with TTL levels in industrial and telecom applications. The ETQF0102 is able to set up different voltage translation levels which makes it very flexible.

The ETQF0102 is available in TSSOP8 (2.95mm × 4.4mm) or VSSOP8 (2.0mm × 2.3mm) package.

Features

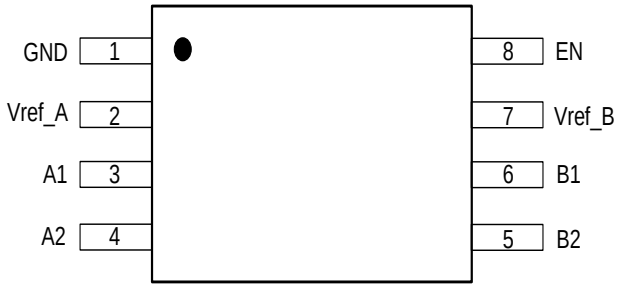
- No Directional Control Required
- Allows Bidirectional Voltage-Level Translation between: 0.95V~3.3V ↔ 1.8V~5V
- Low Standby Current
- 5V Tolerance I/O Port to Support TTL
- Low RON Provides Less Signal Distortion
- I^3C compatible (12.5MHz Supported)
- Automotive AEC-Q100 Grade 1 Qualified
  -- Ambient Temperature Range of -40°C to 125°C
  -- HBM ±2KV PASS
  -- CDM ±1KV PASS
  -- Latch Up Current to ±100mA PASS
- Package Information:

Part No.	Package	MSL
ETQF0102V	TSSOP8 (2.95mm × 4.4mm)	3
ETQF0102U1	VSSOP8 (2.0mm × 2.3mm)	3

Applications

- I2C, I3C, SMBus, PMBus, MDIO, UART, SDIO, GPIO, and other Two-Signal Interfaces
- Enterprise Systems
- Communications Equipment
- Personal Computers
- Industrial Automation

Pin Configuration



TSSOO8/VSSOP8

Top view

Figure1.Pin Configuration

Pin Function

Pin No. TSSOP8/VSSOP8	Pin Name	Pin Function
GND	1	Ground Pin.
Vref_A	2	Reference Supply Voltage.
An	3,4	Auto-Bidirectional Data Port.
Bn	5,6	Auto-Bidirectional Data Port.
Vref_B	7	Reference Supply Voltage.
EN	8	Enable Input; Connect to Vref_B and pull-up through a high resistor(200kΩ).

Block Diagram

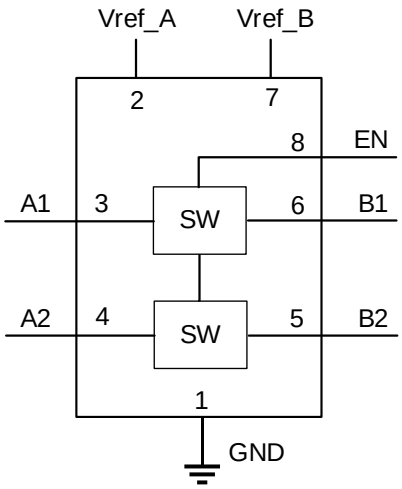


Figure2. Block Diagram

Functional Description

The ETQF0102 can be used in level-translation applications for interfacing devices or systems operating with one another that operate at different interface voltages. The ETQF0102 is ideal for use in applications where an open-drain driver is connected to the data I/Os. The ETQF0102 can also be used in applications where a push-pull driver is connected to the data I/Os.

Auto Bidirectional Voltage Translation

The device is an auto bidirectional voltage level translator that is operational from 0.95 to 5.5V on Vref_A and 1.8 to 5.5V on Vref_B. This allows bidirectional voltage translation between 0.95V and 5.5V without the need for a direction pin in open-drain or push-pull applications. Both the output driver of the controller and the peripheral device output can be push-pull or open-drain (pull-up resistors may be required). In both up and down translation, the B-side is often referred to as the high side and refers to devices connected to the B ports. The A-side can be referred to as the low side.

Output Enable

To enable the I/O pins, the EN input should be tied directly to Vref_B during operation and both pins must be pulled up to the HIGH side (VCCB) through a bias resistor (typically 200kΩ). To be in the high impedance state during power-up, power-down, or during operation, the EN pin must be LOW. The EN pin should always be tied directly to the Vref_B pin and is recommended to be disabled by an open-drain driver without a pullup resistor. This allows Vref_B to regulate the EN input and bias the channels for proper translation. A filter capacitor on Vref_B is recommended for a stable supply at the device.

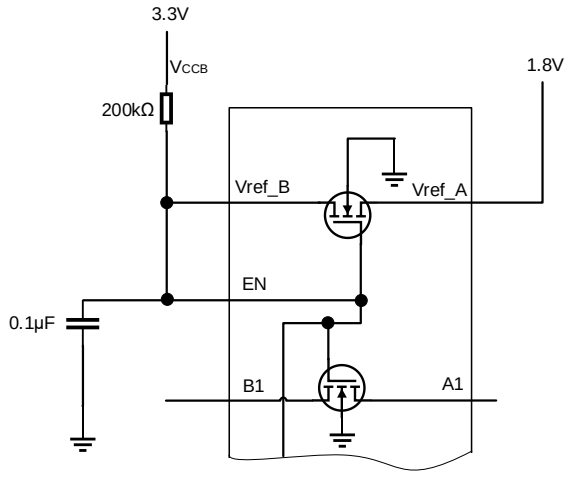


Figure3. Enable Pin Tied to Vref_B Directly and to VCCB Through a Bias Resistor

The supply voltage of open drain I/O devices can be completely different from the supplies used for the ETQF0102 and has no impact on the operation.

Table1. Enable Pin Function Table(EN is controlled by Vref_B logic levels.)

EN PIN	Data Port State
Tied directly to Vref_B	An = Bn
L	Hi-Z

Device Functional Modes

For each channel (n), when either the An or Bn port is LOW, the switch provides a low impedance path between the An and Bn ports; the corresponding Bn or An port will be pulled LOW. The low RON of the switch allows connections to be made with minimal propagation delay and signal distortion. Table 2. provides a summary of device operation.

Table2. Device Functionality

Signal Direction[(1)]	Input State	Switch State	Functionality
B to A (Down Translation)	B = LOW	ON (Low Impedance)	A-side voltage is pulled low through the switch to the B-side voltage
	B = HIGH	OFF (High Impedance)	A-side voltage is clamped at V_{ref_A} [(2)]
A to B (Up Translation)	A = LOW	ON (Low Impedance)	B-side voltage is pulled low through the switch to the A-side voltage
	A = HIGH	OFF (High Impedance)	B-side voltage is clamped at V_{ref_A} and then pulled up to the V_{PU} supply voltage

Note1: The downstream channel should not be actively driven through a low impedance driver, or else bus contention may occur.

Note2: The A-side can have a pull-up to Vref_A for additional current drive capability or may also be pulled above Vref_A with a pull-up resistor. Specifications in the Recommended Operating Conditions section should always be followed.

Up Translation

When the signal is being driven from A to B and the An port is HIGH, the switch will be OFF and the Bn port will then be driven to a voltage higher than Vref_A by the pull-up resistor that is connected to the pull-up supply voltage (V_{PU}). This functionality allows seamless translation between higher and lower voltages selected by the user, without the need for directional control. Pull-up resistors are always required on the high side, and pull-ups are only required on the low side, if the low side of the device's output is open drain or its input has a leakage greater than 1μA.

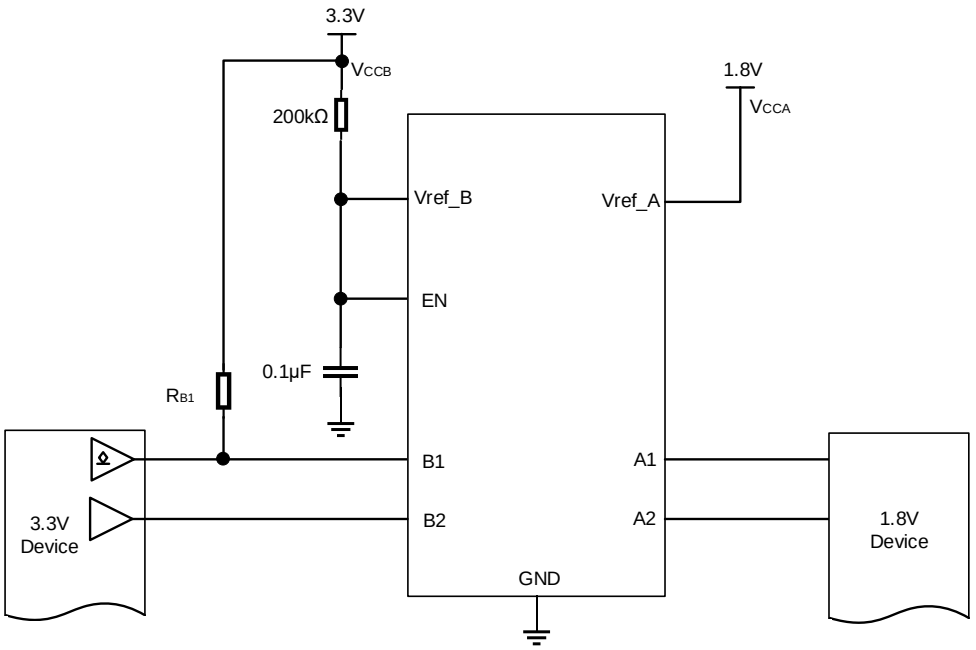


Figure4. Up Translation Example Schematic with Push-Pull and Open Drain Configuration

Up translation with the ETQF0102 requires attention to two important factors: maximum data rate and sink current. Maximum data rate is directly related to the rising edge of the output signal. Sink current depends on supply values and the chosen pull-up resistor values. Equation1 shows the maximum data rate formula and Equation2 shows the maximum sink current formula, both of which are estimations. A low RC value is needed to reach high speeds, which also require strong drivers.

$$\frac{1}{3\times 2R_{B1}C_{B1}} \equiv \frac{1}{6R_{B1}C_{B1}}\left(\frac{\text{bits}}{\text{sec}\,ond}\right) \quad \textbf{(1)}$$

$$I_{OL} \cong \frac{VCCA}{R_{A1}} + \frac{VCCB}{R_{B1}}(A) \quad \textbf{(2)}$$

Down Translation

When the signal is being driven HIGH from the Bn port to An port, the switch will be OFF, clamping the voltage on the An port to the voltage set by Vref_A. A pull-up resistor can be added on either side of the device. There are special circumstances that allow the removal of one or both of the pull-up resistors. If the signal is always going to be down translated from a push-pull transmitter, then the resistor on the B-side can be removed. If the leakage current into the receiver on the A-side is less than 1μA, then the resistor on the A-side can also be removed. This arrangement with no external pull-up resistors can be used when down translating from a push-pull output to a low-leakage input. For an open drain transmitter, the pull-up resistor on the B-side is necessary because an open drain output can't drive high by itself.

Absolute Maximum Ratings

Symbol	Parameters	Value	Unit
V_I	Input Voltage	-0.3 to 6.0	V
$V_{I/O}$	Input/Output Voltage	-0.3 to 6.0	V
I_O	Continuous Channel Current	0 to 128	mA
I_{IK}	Input Clamp Current	-50	mA
T_{STG}	Storage Temperature Range	-65 to 150	ºC
T_J	Operating Junction Temperature	-40 to 150	ºC
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance	150	°C/W
V_{ESD}	Human Body Mode(3)	±2000	V
	Charged Device Mode(4)	±1000	V
Latch-up	Latch-up Current(5)	±100	mA

Note3: HBM tested per AEC-Q100-002(JEDEC JS-001);

Note4: CDM tested per AEC-Q100-011(JEDEC JS-002);

Note5: Latch up Current Maximum Rating tested per AEC-Q100-004(JEDEC JESD78F).

Recommended Operating Conditions

Symbol	Parameters	Rating	Unit
$V_{I/O}$	Input/Output Voltage	0 to 5.5	V
$V_{ref_A/B/EN}$	Reference Voltage	0 to 5.5	V
I_{pass}	Pass Transistor Current	64	mA
T_A	Operating Ambient Temperature	-40 to 125	ºC
$V_{I/O}$	Input/Output Voltage	0 to 5.5	V
$V_{ref_A/B/EN}$	Reference Voltage	0 to 5.5	V

Electrical Characteristics

T_A = -40ºC~125ºC, from A to B or B to A (unless otherwise noted, all typical values are at T_A = 25°C.)

Symbol	Parameters	Conditions		Min	Typ	Max	Unit
V_{IK}	I/O Input Clamp Voltage	I_I = -18mA, V_{EN} = 0V				-1.2	V
I_{IH}	Input Leakage Current	V_I = 5V, V_{EN} = 0V				5.0	uA
I_{CC}	Input Current	V_{ref_B} = V_{EN} = 5.5V, V_{ref_A} = 4.5V, I_O = 0mA, V_I = V_{CC} or GND			0.1	1	uA
$C_{I(ref_A/B/EN)}$ (6)	Input Capacitance	V_I = 3V or 0V, T_A = 25°C.			11		pF
$C_{iO(off)}$ (6)	Off Capacitance	V_I = 3V or 0V, V_{EN} = 0V, T_A = 25°C.			4.0	6.0	pF
$C_{iO(on)}$ (6)	On Capacitance	V_I = 3V or 0V, V_{EN} = 3V, T_A = 25°C.			12	17	pF
R_{on}(7)	On-State Resistance	V_I = 0V, I_O = 64mA	V_{ref_A} = 3.3V; V_{ref_B} = V_{EN} = 5V		3.0	7.0	Ω
			V_{ref_A} = 1.8V; V_{ref_B} = V_{EN} = 5V		4.0	10	
			V_{ref_A} = 1.0V; V_{ref_B} = V_{EN} = 5V		5.0	25	
		V_I = 0V, I_O = 32mA	V_{ref_A} = 1.8V; V_{ref_B} = V_{EN} = 5V		4.0	9.0	
			V_{ref_A} = 2.5V; V_{ref_B} = V_{EN} = 5V		3.0	8.0	
		V_I = 1.8V, I_O = 15mA	V_{ref_A} = 3.3V; V_{ref_B} = V_{EN} = 5V		4.0	13	
		V_I = 1.0V, I_O = 10mA	V_{ref_A} = 1.8V; V_{ref_B} = V_{EN} = 3.3V		7.0	24	
		V_I = 0V, I_O = 10mA	V_{ref_A} = 1.0V; V_{ref_B} = V_{EN} = 3.3V		5.0	18	
		V_I = 0V, I_O = 10mA	V_{ref_A} = 1.0V; V_{ref_B} = V_{EN} = 1.8V		6.0	19	

Note6: Guaranteed by design and characterization, not a FT item.

Note7: Measured by the voltage drop between the A and B pins at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) pins.

AC Performance (Translating Down) Switching Characteristics

T_A = -40ºC~125ºC, from B to A, R_L=1KΩ (unless otherwise noted, all typical values are at T_A = 25°C.)

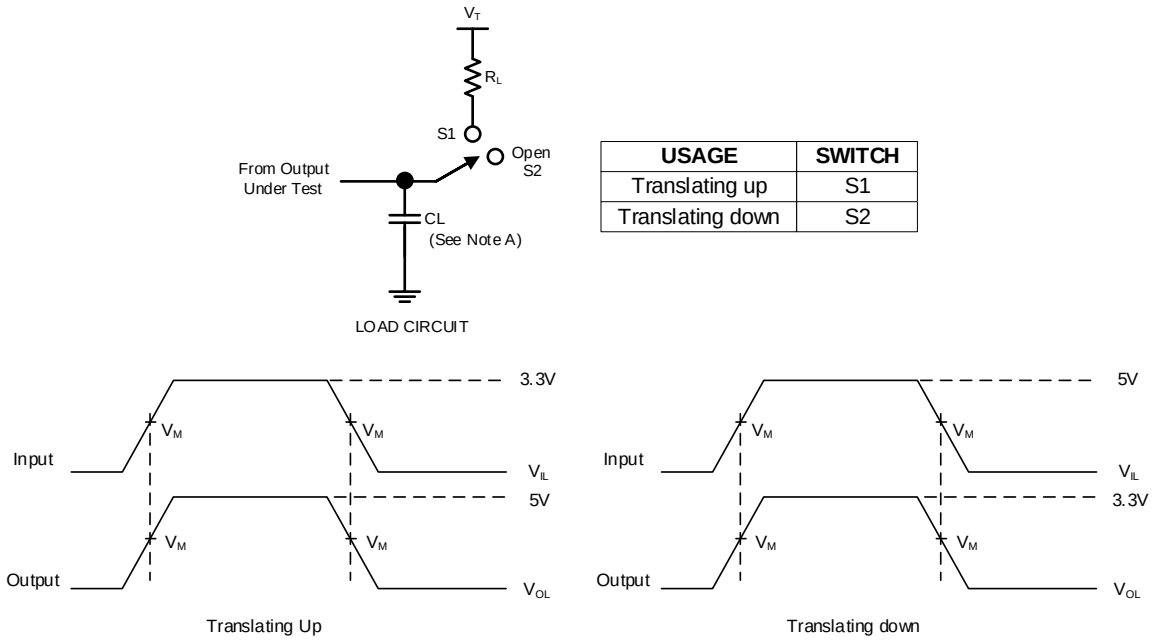
Symbol	Parameters	Conditions		Min	Typ	Max	Unit
t_{PLH}	Low-to-High Propagation Delay	V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 0.95V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.6	1.5	ns
			C_L = 30pF		0.8	2.0	
			C_L = 50pF		1.0	2.5	
		V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 1.2V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.8	1.5	
			C_L = 30pF		1.4	2.5	
			C_L = 50pF		3.0	4.0	
		V_{CCB} = V_{IH} =3 .3V, V_{CCA} = 1.8V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.3	1.2	
			C_L = 30pF		0.5	2.0	
			C_L = 50pF		0.9	2.5	
		V_{CCB} = V_{IH} = 5V, V_{CCA} = 3.3V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.8	1.2	
			C_L = 30pF		1.0	1.5	
			C_L = 50pF		1.2	2.0	
t_{PHL}	High-to-Low Propagation Delay	V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 0.95V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.4	2.5	
			C_L = 30pF		1.0	3.0	
			C_L = 50pF		2.0	4.0	
		V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 1.2V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.7	2.0	
			C_L = 30pF		1.3	3.0	
			C_L = 50pF		2.0	4.0	
		V_{CCB} = V_{IH} = 3.3V, V_{CCA} = 1.8V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.4	2.0	
			C_L = 30pF		0.9	2.5	
			C_L = 50pF		1.5	3.0	
		V_{CCB} = V_{IH} = 5V, V_{CCA} = 3.3V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.4	1.5	
			C_L = 30pF		1.0	2.5	
			C_L = 50pF		1.4	3.0	

AC Performance (Translating Up) Switching Characteristics

T_A = -40ºC~125ºC, from A to B, R_L=1KΩ (unless otherwise noted, all typical values are at T_A = 25°C.)

Symbol	Parameters	Conditions		Min	Typ	Max	Unit
t_{PLH}	Low-to-High Propagation Delay	V_{CCB} = 1.8V, V_{CCA} = V_{IH} = 0.95V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.8	1.5	ns
			C_L = 30pF		1.0	2.0	
			C_L = 50pF		1.2	3.0	
		V_{CCB} = 1.8V, V_{CCA} = V_{IH} = 1.2V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		1.1	1.5	
			C_L = 30pF		1.3	2.0	
			C_L = 50pF		1.9	3.0	
		V_{CCB} = 3.3V, V_{CCA} = V_{IH} = 1.8V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.6	1.0	
			C_L = 30pF		0.8	1.5	
			C_L = 50pF		1.0	2.0	
		V_{CCB} = 5V, V_{CCA} = V_{IH} = 3.3V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.6	1.5	
			C_L = 30pF		0.8	2.5	
			C_L = 50pF		1.2	3.0	
t_{PHL}	High-to-Low Propagation Delay	V_{CCB} = 1.8V, V_{CCA} = V_{IH} = 0.95V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		2.0	3.5	
			C_L = 30pF		2.8	4.5	
			C_L = 50pF		4.2	6.5	
		V_{CCB} = 1.8V, V_{CCA} = V_{IH} = 1.2V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		1.7	3.0	
			C_L = 30pF		2.6	3.5	
			C_L = 50pF		4.2	4.5	
		V_{CCB} = 3.3V, V_{CCA} = V_{IH} = 1.8V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		1.2	3.0	
			C_L = 30pF		1.8	4.0	
			C_L = 50pF		2.6	5.0	
		V_{CCB} = 5V, V_{CCA} = V_{IH} = 3.3V, V_{IL} = 0V, and V_M = 0.5V_{CCA}	C_L = 20pF		0.8	2.0	
			C_L = 30pF		1.2	3.0	
			C_L = 50pF		1.8	4.0	

AC Performance Test Circuit



USAGE	SWITCH
Translating up	S1
Translating down	S2

Note A: CL includes probe and jig capacitance.

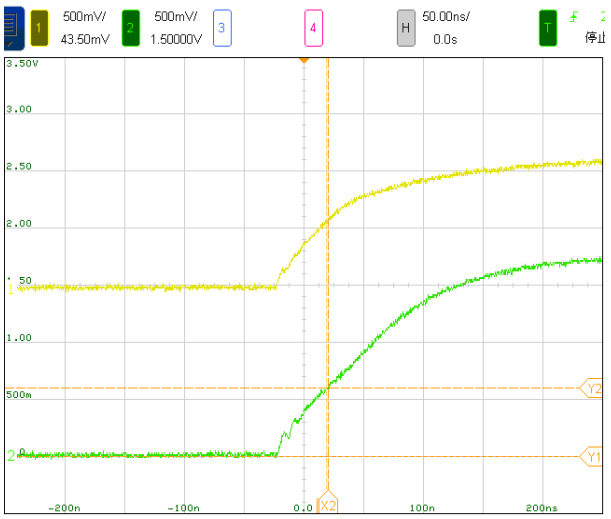
Note B: Generators that have the following characteristics generate all input pulses: PRR ≤ 10MHs, Zo = 50Ω, t_r ≤ 2ns, t_f ≤ 2ns.

Note C: The outputs are measured one at a time, with one transition per measurement.

Figure5. AC Performance Load Circuit for Outputs

Typical Characteristics

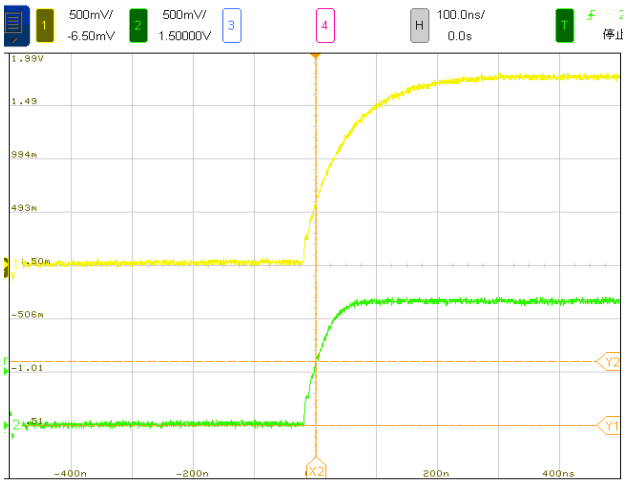
(V_{CCB} = 1.8V, V_{CCA} = 1.2V, C_L = 50pF, R_{PU} = 1kΩ, C_L = 50pF unless otherwise noted T_A = 25°C.)



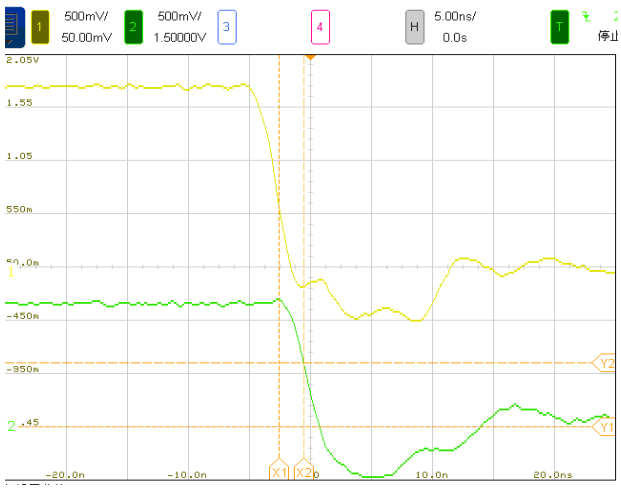
AC Performance t_{PLH} 1.2V to 1.8V



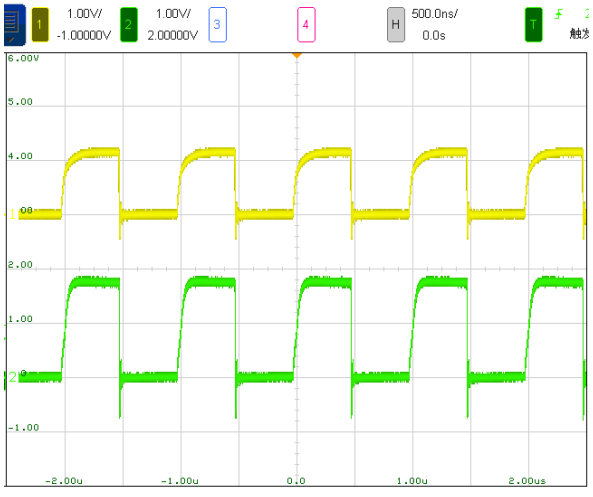
AC Performance t_{PHL} 1.2V to 1.8V



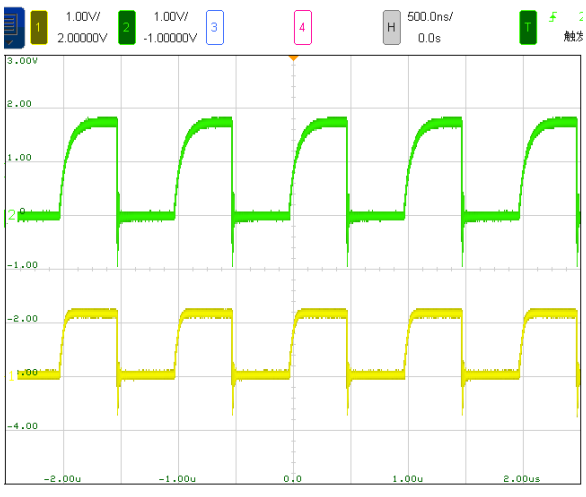
AC Performance t_{PLH} 1.8V to 1.2V



AC Performance t_{PHL} 1.8V to 1.2V



Voltage Translation, 1.2V to 1.8V, f = 1MHz



Voltage Translation, 1.8V to 1.2V, f = 1MHz

Application Circuits

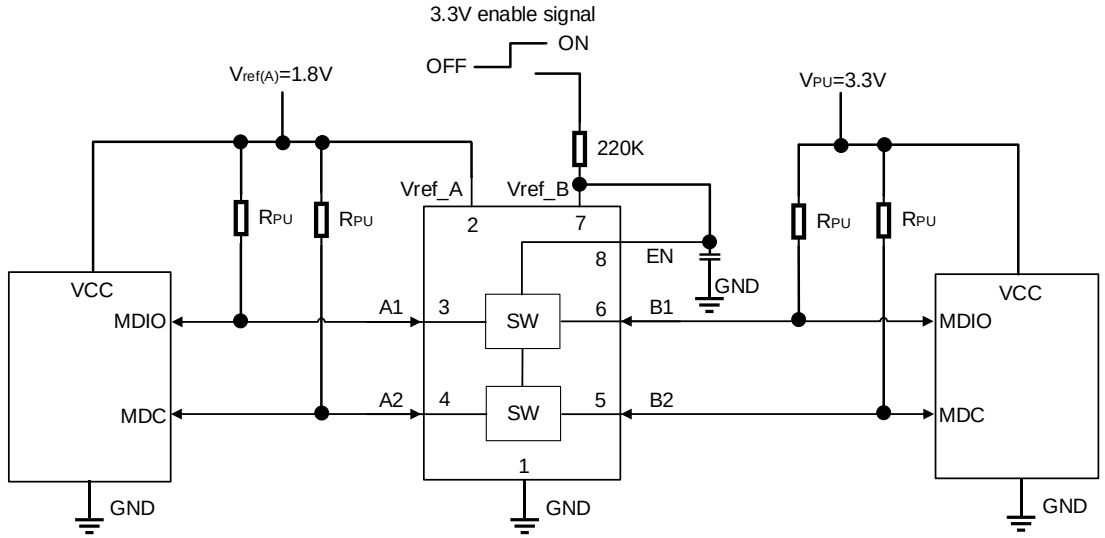


Figure6. Typical Application Circuit for Open-Drain Translation (MDIO Shown as an Example)

In the previous figure, Vref_B is connected through a 200kΩ resistor to a 3.3V power supply and Vref_A is set to 1.8V. The A1 and A2 channels have a maximum output voltage equal to Vref_A and the B1 and B2 channels have has a maximum output voltage equal to V_{PU}.

The ETQF0102 has an EN input that is used to disable the device by setting EN LOW, placing all I/Os in the high-impedance state. Since the ETQF0102 of devices are switch-type voltage translators, the power consumption is very low.

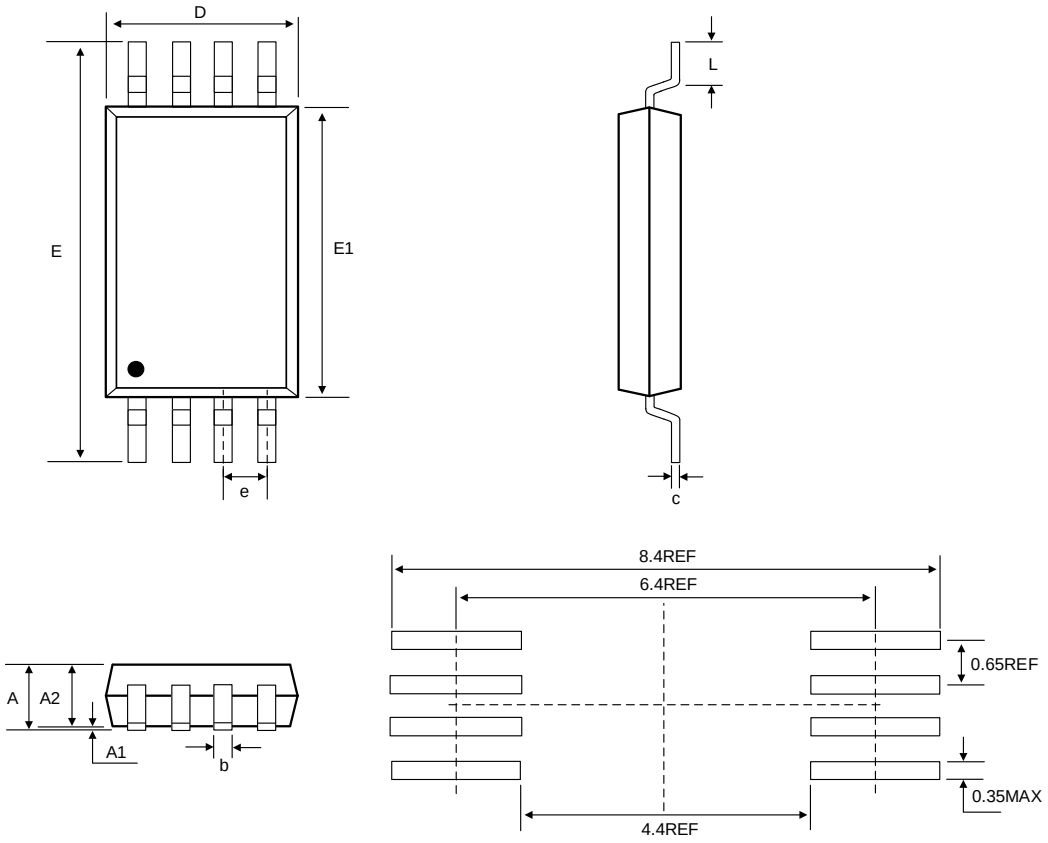
Table3. Application Operating Condition

Symbol	Parameters	Min	Typ	Max	Unit
V_{ref_A}[8]	Reference Voltage (A)	0.9		5.5	V
V_{ref_B}	Reference Voltage (B)	V_{ref_A} + 0.8		5.5	V
$V_{I(EN)}$	Input Voltage on EN Pin	V_{ref_A} + 0.8		5.5	V
V_{PU}	Pull-Up Supply Voltage	0		V_{ref_B}	V

Note8: V_{ref_A} is required to be the lowest voltage level across all inputs and outputs. The 200kΩ, bias resistor is required to allow V_{ref_B} to regulate the EN input and properly bias the device for translation.

Package Dimension

TSSOP8 (2.95mm × 4.4mm)

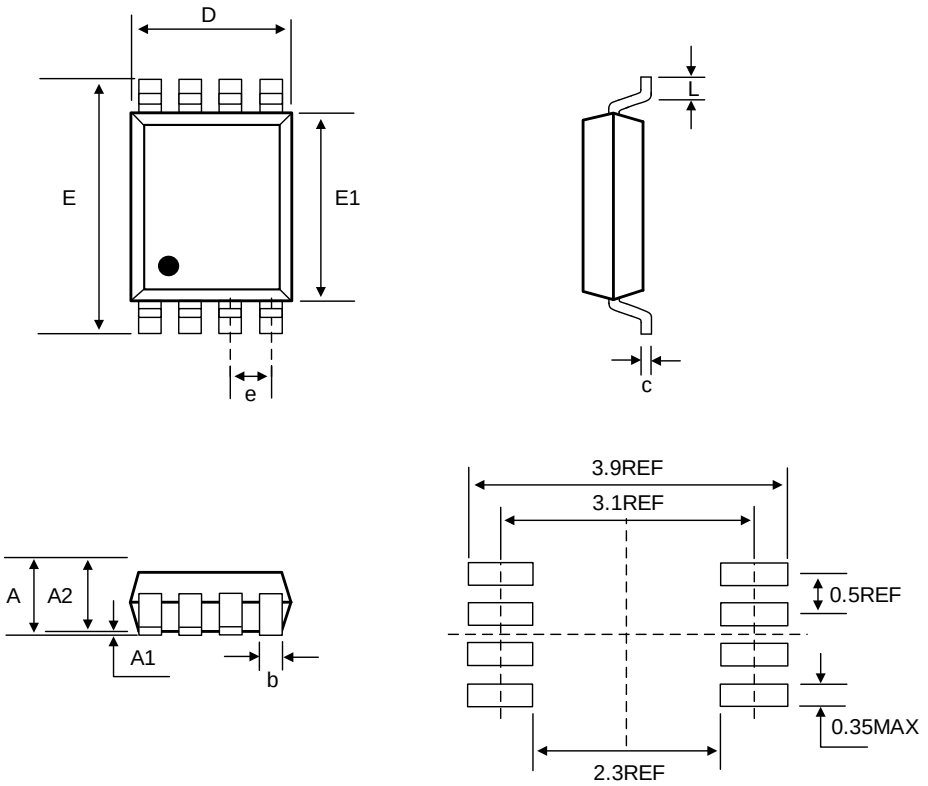


COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	-	-	1.25
A1	0.00	-	0.15
A2	0.80	0.95	1.10
b	0.19	-	0.30
c	0.08	-	0.20
D	2.80	2.95	3.10
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.33	-	0.75

VSSOP8 (2.0mm × 2.3mm)



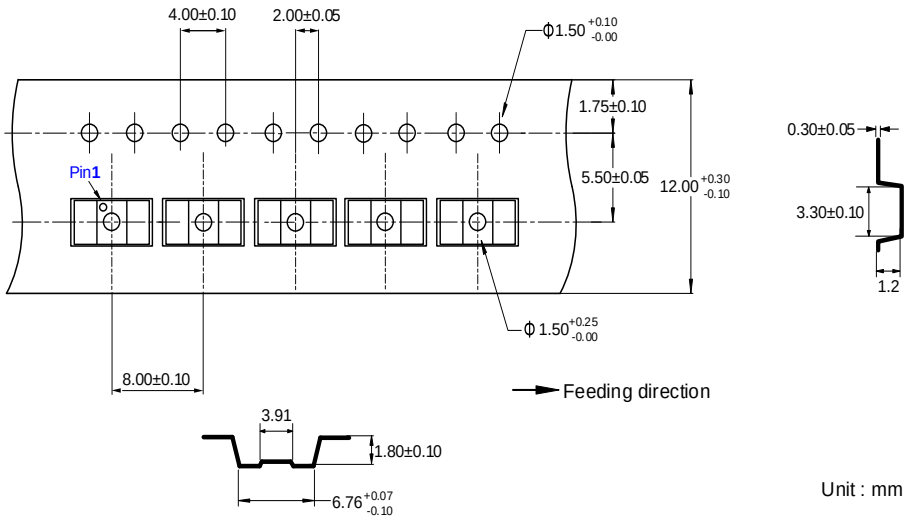
COMMON DIMENSIONS

(Unit: mm)

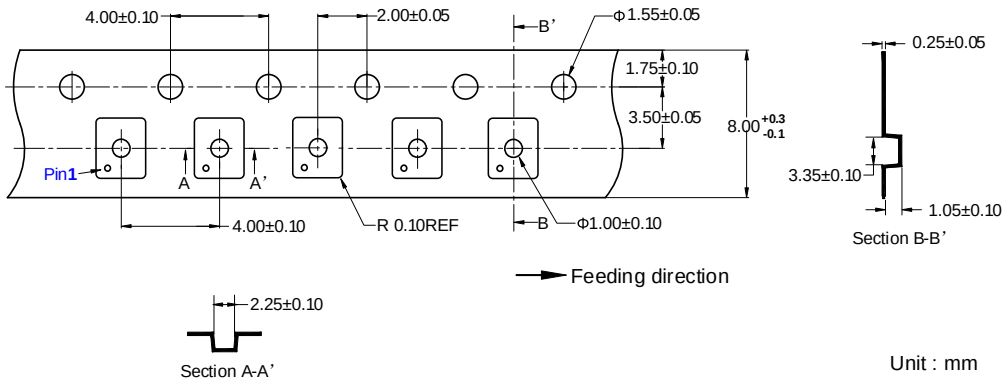
SYMBOL	MIN	NOM	MAX
A	-	-	0.9
A1	-	-	0.1
A2	0.65	0.75	0.8
b	0.17	-	0.25
c	0.1	-	0.18
D	1.9	2	2.1
E1	2.2	2.3	2.4
E	3	3.1	3.2
e	0.4	0.5	0.6
L	0.20	0.26	0.35
θ	0°	-	6°

Tape Information

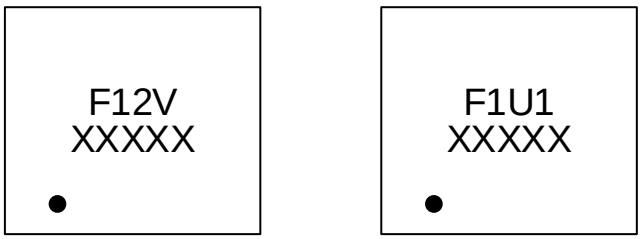
TSSOP8 (2.95mm × 4.4mm)



VSSOP8 (2.0mm × 2.3mm)



Marking Information



F12V = Part Number
XXXXX = Tracking Number

F1U1 = Part Number
XXXXX = Tracking Number

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2025.05.09	Initial Version	Hu chengyu	Liu yiguo	Liu jiaying
1.1	2026-01-05	Update Format and Package, Add Tape	Xu tao	Yang xiaoxu	Liu jiaying
1.2	2026-04-22	Update Package	Lu shaojie	Yang xiaoxu	Liu jiaying
1.3	2026-05-18	Update Package	Lu shaojie	Yang xiaoxu	Liu jiaying